

on-chip resistor NPN silicon epitaxial transistor
For mid-speed switching

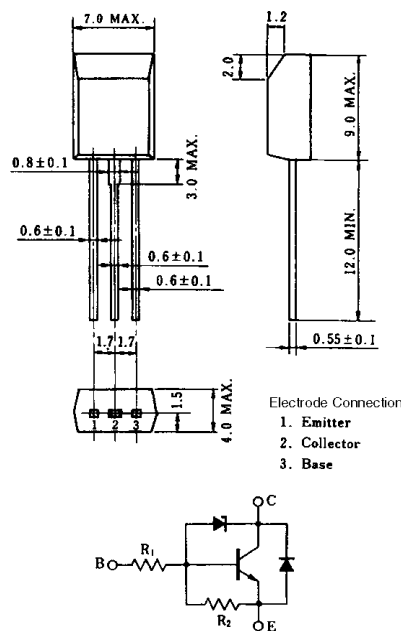
The CE1F3P is a transistor of on-chip high hFE resistor incorporating dumper diode in collector to emitter and zener diode in collector to base as protect elements. This transistor is ideal for actuator drives of OA equipments and electric equipments.

* PW≤10 ms, duty cycle≤50 %

FEATURES

- On-chip zener diode for surge voltage absorption
- On-chip bias resistor: R1 = 2.2 kΩ, R2 = 10 kΩ
- Low power consumption during driving:
VOL = 0.12 V @VI = 5.0 V, IC = 0.5 A
- On-chip dumper diode for reverse cable

PACKAGE DRAWING (UNIT: mm)



ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	V _{CB0}	60±10	V
Collector to emitter voltage	V _{CEO}	60±10	V
Emitter to base voltage	V _{EBO}	15	V
Collector current (DC)	I _{C(DC)}	±2.0	A
Collector current (Pulse)	I _{C(pulse)} *	±3.0	A
Base current (DC)	I _{B(DC)}	0.03	A
Total power dissipation	P _T	1.0	W
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

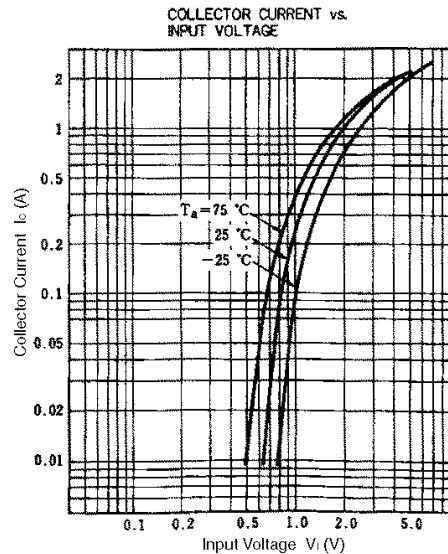
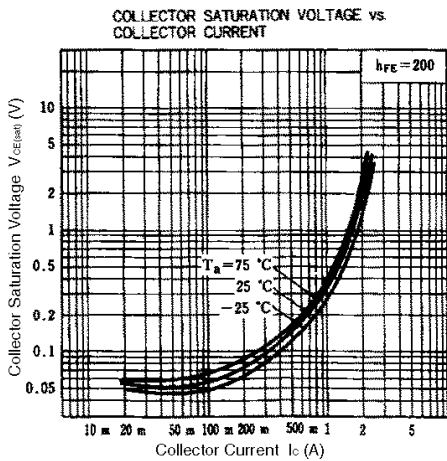
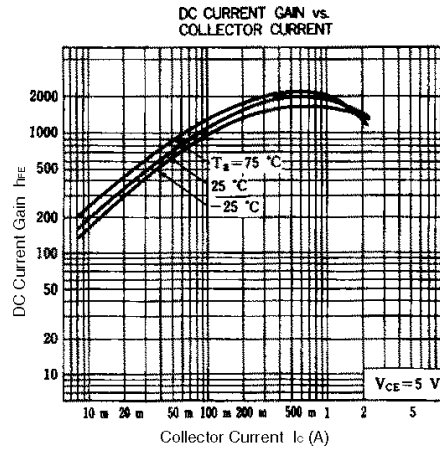
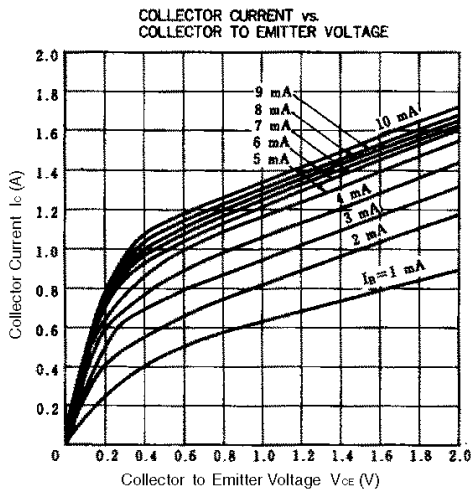
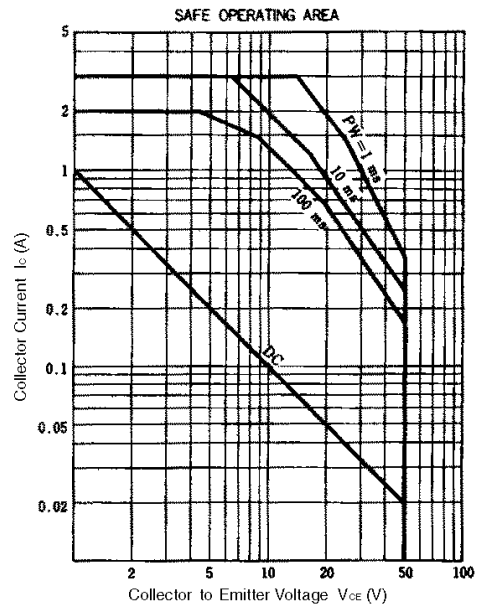
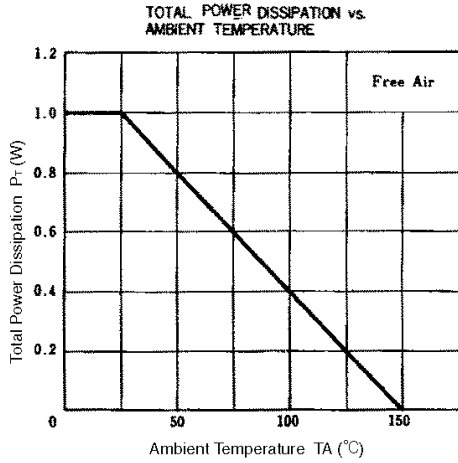
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to emitter voltage	V _{CEO(SUS)}	I _C = 2.0 A, I _B = 5.0 mA, L = 6.0 mH	50	60		V
Collector cutoff current	I _{CB0}	V _{CB} = 40 V, I _E = 0			100	nA
DC current gain	h _{FE1} **	V _{CE} = 5.0 V, I _C = 0.2 A	700	1200		-
DC current gain	h _{FE2} **	V _{CE} = 5.0 V, I _C = 1.0 A	1000	1600	3000	-
DC current gain	h _{FE3} **	V _{CE} = 5.0 V, I _C = 2.0 A	500	1200		-
Low level output voltage	V _{OL} **	V _I = 5.0 V, I _C = 0.5 A		0.12	0.3	V
Low level input voltage	V _{IL} **	V _{CE} = 12 V, I _C = 100 μA		0.5	0.4	V
Input resistance 1	R ₁		1.54	2.2	2.86	kΩ
Input resistance 2	R ₂		7.0	10.0	13.0	kΩ
Turn-on time	t _{on}	I _C = 1.0 A		0.4		μs
Storage time	t _{stg}	I _{B1} = -I _{B2} = 10 mA		1.4		μs
Fall time	t _f	V _{CC} = 20 V, R _L = 20 Ω		0.5		μs

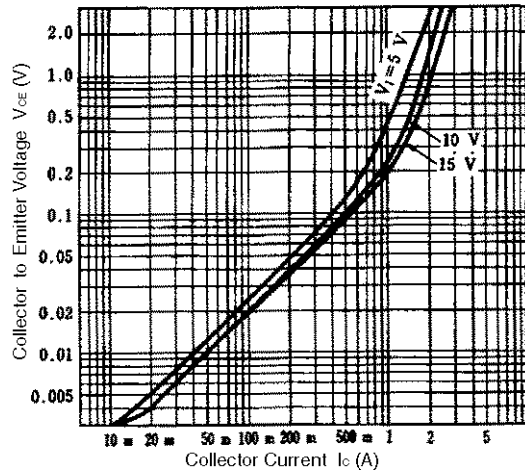
** Pulse test PW ≤ 350 μs, duty cycle ≤ 2 %

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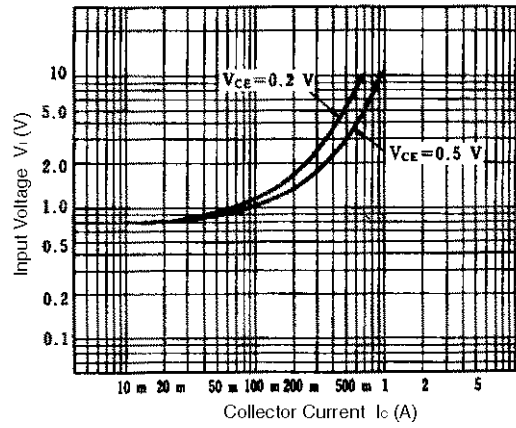
TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)



COLLECTOR TO EMITTER VOLTAGE vs. COLLECTOR CURRENT



INPUT VOLTAGE vs. COLLECTOR CURRENT



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